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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## LOW DROP POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

<b>I<sub>F(AV)</sub></b>	<b>3 A</b>
<b>V<sub>RRM</sub></b>	<b>25 V</b>
<b>T<sub>j (max)</sub></b>	<b>150°C</b>
<b>V<sub>F (max)</sub></b>	<b>0.44 V</b>

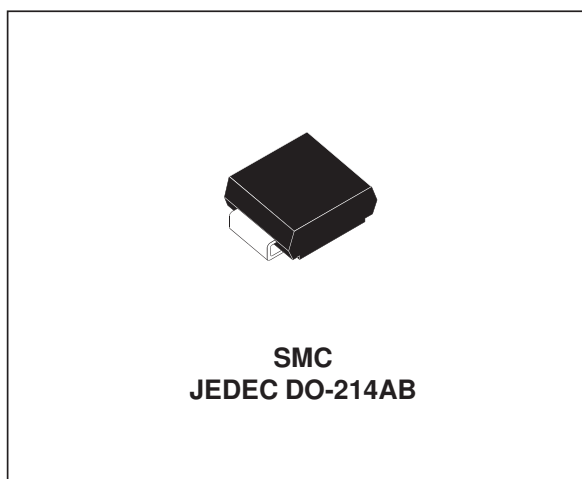
### FEATURES AND BENEFITS

- VERY LOW FORWARD VOLTAGE DROP FOR LESS POWER DISSIPATION
- OPTIMIZED CONDUCTION/REVERSE LOSSES TRADE-OFF WHICH MEANS THE HIGHEST EFFICIENCY IN THE APPLICATIONS
- HIGH POWER SURFACE MOUNT MINIATURE PACKAGE
- AVALANCHE CAPABILITY SPECIFIED

### DESCRIPTION

Single Schottky rectifier suited to Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in SMC, this device is especially intended for use as an antiparallel diode on synchronous rectification freewheel MOSFET's at the secondary of 3.3V SMPS and DC/DC units.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		25	V
I <sub>F(RMS)</sub>	RMS forward current		10	A
I <sub>F(AV)</sub>	Average forward current	T <sub>L</sub> = 115°C δ = 0.5	3	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms Sinusoidal	75	A
I <sub>R(RM)</sub>	Repetitive peak reverse current	tp = 2 μs square F=1kHz	1	A
I <sub>R(SM)</sub>	Non repetitive peak reverse current	tp = 100 μs square	1	A
T <sub>stg</sub>	Storage temperature range		- 65 to + 150	°C
P <sub>ARM</sub>	Repetitive peak avalanche power	tp = 1 μs T <sub>j</sub> = 25°C	1500	W
T <sub>j</sub>	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

# STPS3L25S

## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-l)}$	Junction to lead	20	°C/W

## STATIC ELECTRICAL CHARACTERISTICS

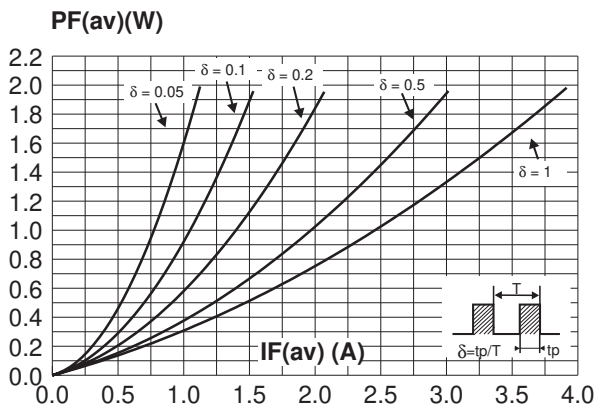
Symbol	Tests Conditions	Tests Conditions	Min.	Typ.	Max.	Unit
$I_R^*$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$		90	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$		15	30	$\text{mA}$
$V_F^*$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 3\text{ A}$		0.49	V
		$T_j = 125^\circ\text{C}$		0.37	0.44	
		$T_j = 25^\circ\text{C}$	$I_F = 6\text{ A}$		0.6	
		$T_j = 125^\circ\text{C}$		0.5	0.58	

Pulse test: \*  $t_p = 380\ \mu\text{s}$ ,  $\delta < 2\%$

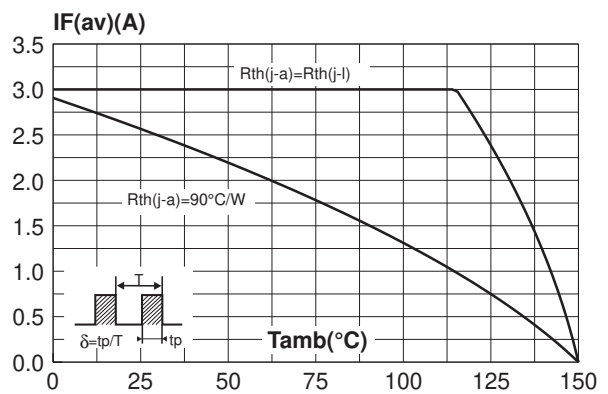
To evaluate the maximum conduction losses use the following equation :

$$P = 0.3 \times I_{F(AV)} + 0.047 \times I_{F(RMS)}^2$$

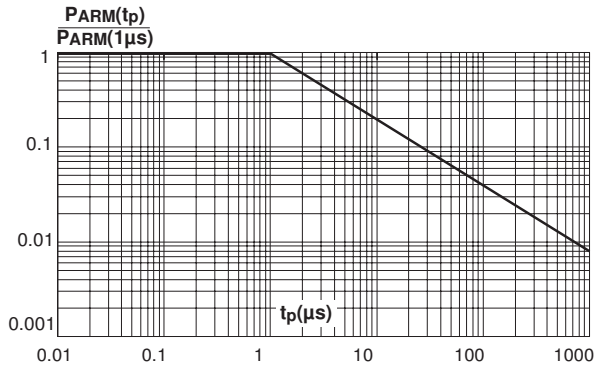
**Fig. 1:** Average forward power dissipation versus average forward current.



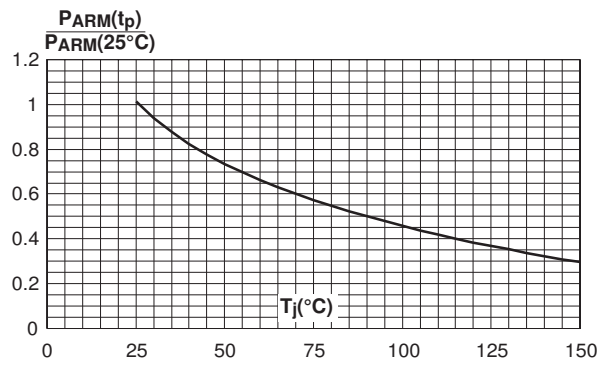
**Fig. 2:** Average forward current versus ambient temperature ( $\delta=0.5$ ).



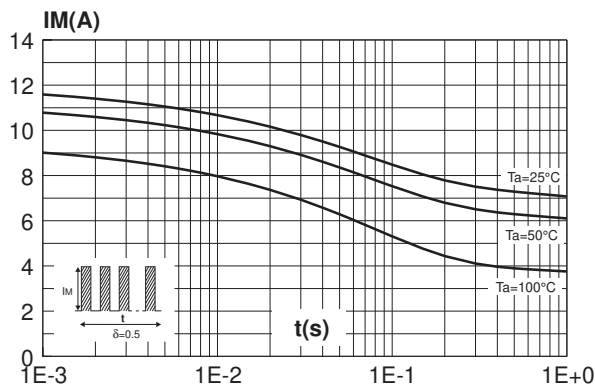
**Fig. 3:** Normalized avalanche power derating versus pulse duration.



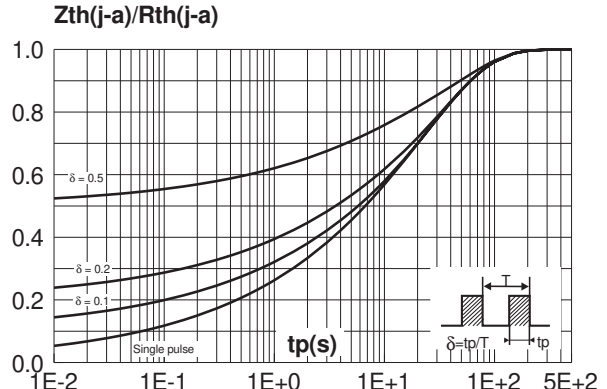
**Fig. 4:** Normalized avalanche power derating versus junction temperature.



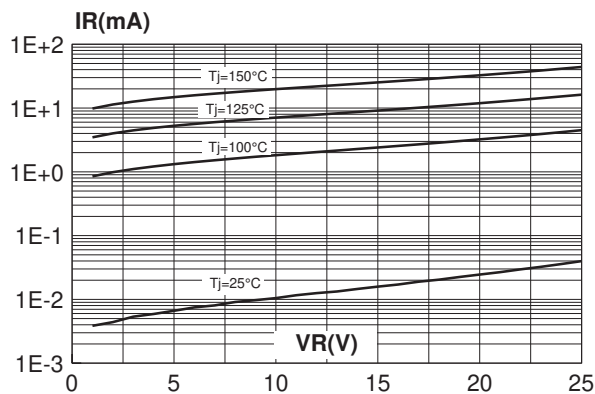
**Fig. 5:** Non repetitive surge peak forward current versus overload duration (maximum values).



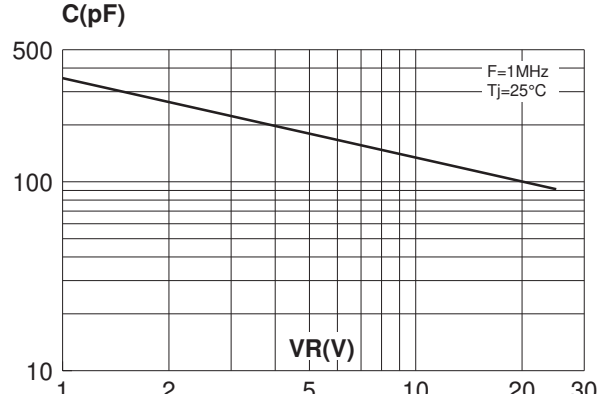
**Fig. 6:** Relative variation of thermal impedance junction to ambient versus pulse duration.



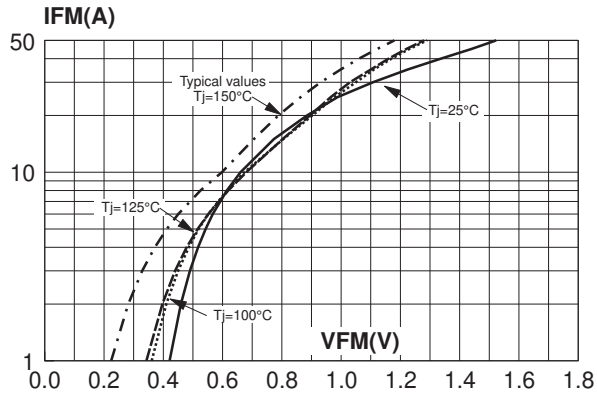
**Fig. 7:** Reverse leakage current versus reverse voltage applied (typical values).



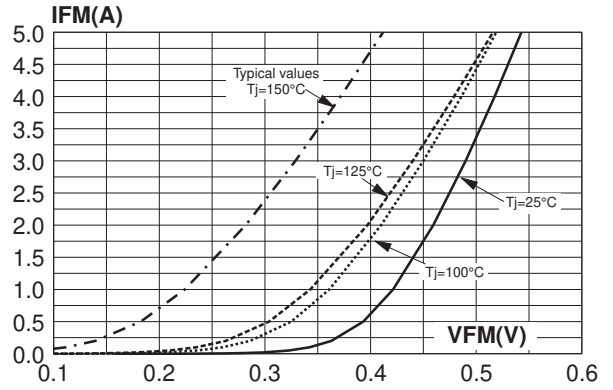
**Fig. 8:** Junction capacitance versus reverse voltage applied (typical values).



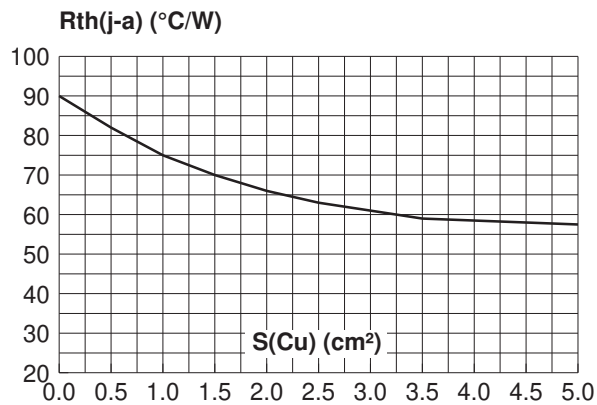
**Fig. 9-1:** Forward voltage drop versus forward current (maximum values, high level).



**Fig. 9-2:** Forward voltage drop versus forward current (maximum values, low level).

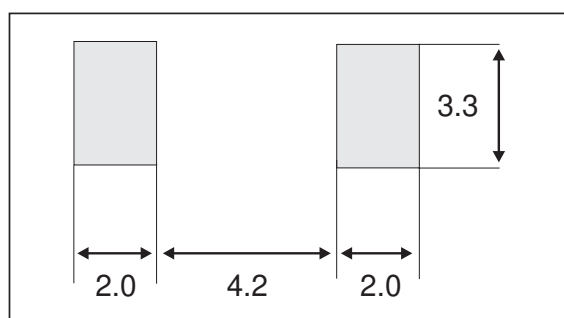


**Fig. 10:** Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness:



**PACKAGE MECHANICAL DATA**  
 SMC

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	2.90	3.2	0.114	0.126
c	0.15	0.41	0.006	0.016
E	7.75	8.15	0.305	0.321
E1	6.60	7.15	0.260	0.281
E2	4.40	4.70	0.173	0.185
D	5.55	6.25	0.218	0.246
L	0.75	1.60	0.030	0.063

**FOOT PRINT DIMENSIONS** (in millimeters)


Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS3L25S	S23	SMC	0.243g	2500	Tape & reel

- BAND INDICATES CATHODE
- EPOXY MEETS UL94,V0

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